NSN 5961-00-403-2543

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-403-2543 **Inclosure Material:** Metal **Overall Length:** 0.415 inches **Overall Diameter:** 0.245 inches **Mounting Method:** Compression **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 regulator voltage **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Test Data Document:** 45413-134240 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure:**